

## High Frequency Chip Inductor / CF TYPE

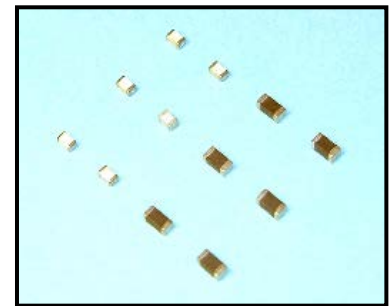
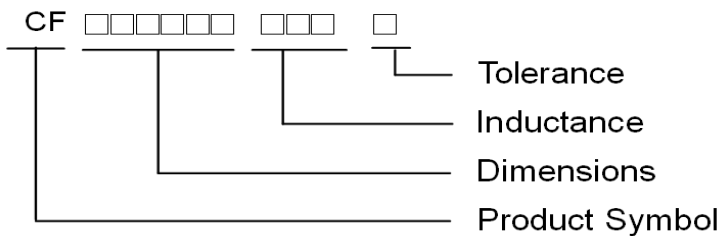
### Features:

1. Closed magnetic circuit avoids crosstalk.
2. S.M.T. type.
3. Excellent solderability and heat resistance.
4. High reliability.
5. The products contain no lead and also support lead-free soldering.
6. Supports operating frequency up to 6GHz with nominal inductance values from 1.0nH to 470nH.

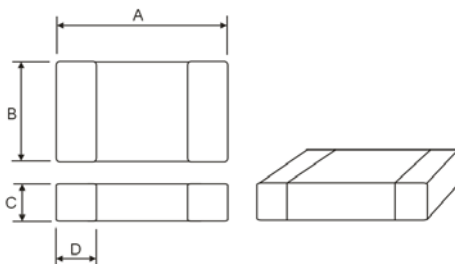
### Applications:

1. Prevention of electromagnetic interference to signals on the secondary side of electric equipment.
2. RF module of telecommunication products, personal handyphone systems, pagers, cellular phones, computer communications, etc...

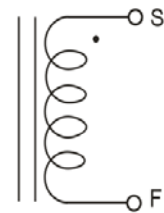
### Product Identification :



### Shape and Dimension



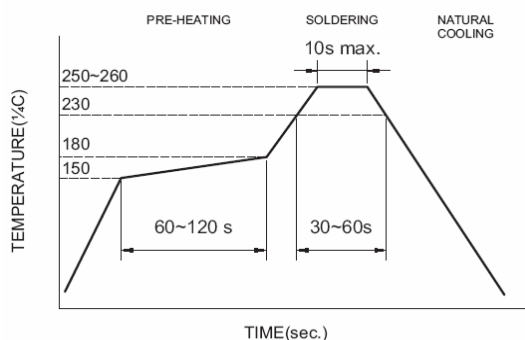
### Schematic



### Dimensions in mm

TYPE	A(mm)	B(mm)	C(mm)	D(mm)
<b>CF100505</b>	1.0±0.1	0.5±0.1	0.5±0.1	0.25±0.1
<b>CF160808</b>	1.6±0.15	0.8±0.15	0.8±0.15	0.3±0.2

### Recommended Reflow



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### Electrical Characteristics (CF100505 TYPE)

Part No.	Inductance (nH)	Tolerance (%) (±)	L,Q Test Freq. (MHz)	Q Min	SRF (MHz)Typ.	DCR (Ω) Max	Rated Current (mA) Max
CF100505T-0N2□	0.2	0.3nH	100 MHz,200 mV	8	10000	0.1	400
CF100505T-0N3□	0.3	0.3nH	100 MHz,200 mV	8	10000	0.1	400
CF100505T-0N4□	0.4	0.3nH	100 MHz,200 mV	8	10000	0.1	400
CF100505T-0N5□	0.5	0.3nH	100 MHz,200 mV	8	10000	0.1	400
CF100505T-0N6□	0.6	0.3nH	100 MHz,200 mV	8	10000	0.1	400
CF100505T-0N7□	0.7	0.3nH	100 MHz,200 mV	8	10000	0.1	400
CF100505T-0N8□	0.8	0.3nH	100 MHz,200 mV	8	10000	0.1	400
CF100505T-1N0□	1	0.3nH	100 MHz,200 mV	8	10000	0.1	400
CF100505T-1N2□	1.2	0.3nH	100 MHz,200 mV	8	10000	0.1	400
CF100505T-1N3□	1.3	0.3nH	100 MHz,200 mV	8	9000	0.1	400
CF100505T-1N5□	1.5	0.3nH	100 MHz,200 mV	8	9000	0.1	400
CF100505T-1N8□	1.8	0.3nH	100 MHz,200 mV	8	8700	0.1	400
CF100505T-2N0□	2	0.3nH	100 MHz,200 mV	8	8100	0.15	400
CF100505T-2N2□	2.2	0.3nH	100 MHz,200 mV	8	8100	0.15	400
CF100505T-2N4□	2.4	0.3nH	100 MHz,200 mV	8	7700	0.15	400
CF100505T-2N7□	2.7	0.3nH	100 MHz,200 mV	8	7700	0.15	400
CF100505T-3N0□	3	0.3nH	100 MHz,200 mV	8	6300	0.15	400
CF100505T-3N3□	3.3	0.3nH,10%	100 MHz,200 mV	8	6300	0.15	400
CF100505T-3N6□	3.6	0.3nH,10%	100 MHz,200 mV	8	6100	0.15	400
CF100505T-3N9□	3.9	0.3nH,10%	100 MHz,200 mV	8	6100	0.2	400
CF100505T-4N3□	4.3	0.3nH,10%	100 MHz,200 mV	8	5400	0.2	400
CF100505T-4N7□	4.7	0.3nH,10%	100 MHz,200 mV	8	5400	0.2	400
CF100505T-5N0□	5	0.3nH,10%	100 MHz,200 mV	8	5100	0.2	400
CF100505T-5N1□	5.1	0.3nH,10%	100 MHz,200 mV	8	5100	0.2	400
CF100505T-5N6□	5.6	0.3nH,10%	100 MHz,200 mV	8	5100	0.2	400
CF100505T-6N0□	6	0.3nH,10%	100 MHz,200 mV	8	4550	0.25	400
CF100505T-6N2□	6.2	5%,10%	100 MHz,200 mV	8	4550	0.25	400
CF100505T-6N8□	6.8	5%,10%	100 MHz,200 mV	8	4550	0.25	400
CF100505T-7N5□	7.5	5%,10%	100 MHz,200 mV	8	4300	0.25	400
CF100505T-8N0□	8	5%,10%	100 MHz,200 mV	8	4100	0.3	300
CF100505T-8N2□	8.2	5%,10%	100 MHz,200 mV	8	4100	0.3	300
CF100505T-9N1□	9.1	5%,10%	100 MHz,200 mV	8	3900	0.35	300
CF100505T-10N□	10	5%,10%	100 MHz,200 mV	8	3900	0.35	300
CF100505T-12N□	12	5%,10%	100 MHz,200 mV	8	3000	0.4	300
CF100505T-15N□	15	5%,10%	100 MHz,200 mV	8	2600	0.5	300
CF100505T-18N□	18	5%,10%	100 MHz,200 mV	8	2350	0.55	300
CF100505T-22N□	22	5%,10%	100 MHz,200 mV	8	2000	0.7	300
CF100505T-27N□	27	5%,10%	100 MHz,200 mV	8	1900	0.8	300
CF100505T-33N□	33	5%,10%	100 MHz,200 mV	8	1700	1	200

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### Electrical Characteristics (CF100505 TYPE)

Part No.	Inductance (nH)	Tolerance (%)	L,Q Test Freq. (MHz)	Q Min	SRF (MHz)Typ.	DCR (Ω) Max	Rated Current (mA) Max
CF100505T-39N□	39	5%,10%	100 MHz,200 mV	8	1600	1.2	150
CF100505T-47N□	47	5%,10%	100 MHz,200 mV	8	1300	1.3	150
CF100505T-56N□	56	5%,10%	100 MHz,200 mV	8	1250	2	150
CF100505T-68N□	68	5%,10%	100 MHz,200 mV	8	1000	2.2	100
CF100505T-82N□	82	5%,10%	100 MHz,200 mV	8	900	2.5	100
CF100505T-R10□	100	5%,10%	100 MHz,200 mV	8	850	2.5	100

### Electrical Characteristics (CF160808 TYPE)

Part No.	Inductance (nH)	Tolerance (%)	L,Q Test Freq. (MHz)	Q Min	SRF (MHz)Typ.	DCR (Ω) Max	Rated Current (mA) Max
CF160808T-1N0□	1	0.3nH	100 MHz,200 mV	8	10000	0.1	600
CF160808T-1N2□	1.2	0.3nH	100 MHz,200 mV	8	10000	0.1	600
CF160808T-1N5□	1.5	0.3nH	100 MHz,200 mV	8	8000	0.1	600
CF160808T-1N6□	1.6	0.2nH,0.3nH	100 MHz,200 mV	8	8000	0.1	600
CF160808T-1N7□	1.7	0.2nH,0.3nH	100 MHz,200 mV	8	8000	0.1	600
CF160808T-1N8□	1.8	0.3nH	100 MHz,200 mV	8	8000	0.1	600
CF160808T-2N2□	2.2	0.3nH	100 MHz,200 mV	8	7200	0.1	600
CF160808T-2N5□	2.5	0.2nH,0.3nH	100 MHz,200 mV	8	6200	0.1	600
CF160808T-2N7□	2.7	0.3nH	100 MHz,200 mV	10	6200	0.1	600
CF160808T-3N3□	3.3	0.3nH,10%	100 MHz,200 mV	10	5200	0.12	600
CF160808T-3N9□	3.9	0.3nH,10%	100 MHz,200 mV	10	5000	0.14	600
CF160808T-4N3□	4.3	0.3nH,10%	100 MHz,200 mV	10	4750	0.16	600
CF160808T-4N7□	4.7	0.3nH,10%	100 MHz,200 mV	10	4750	0.16	600
CF160808T-5N1□	5.1	0.3nH,10%	100 MHz,200 mV	10	4100	0.18	600
CF160808T-5N4□	5.4	0.2nH,0.3nH	100 MHz,200 mV	8	4100	0.18	600
CF160808T-5N6□	5.6	0.3nH,10%	100 MHz,200 mV	10	4100	0.18	600
CF160808T-6N2□	6.2	5%,10%	100 MHz,200 mV	10	3750	0.22	600
CF160808T-6N8□	6.8	5%,10%	100 MHz,200 mV	10	3750	0.22	600
CF160808T-7N5□	7.5	5%,10%	100 MHz,200 mV	10	3300	0.24	600
CF160808T-8N2□	8.2	5%,10%	100 MHz,200 mV	10	3300	0.24	600
CF160808T-10N□	10	5%,10%	100 MHz,200 mV	12	3000	0.26	600
CF160808T-11N5□	11.5	5%,10%	100 MHz,200 mV	8	2800	0.3	1000
CF160808T-12N□	12	5%,10%	100 MHz,200 mV	12	2600	0.28	600
CF160808T-15N□	15	5%,10%	100 MHz,200 mV	12	2500	0.32	600
CF160808T-18N□	18	5%,10%	100 MHz,200 mV	12	2400	0.35	600
CF160808T-22N□	22	5%,10%	100 MHz,200 mV	12	2000	0.4	500
CF160808T-27N□	27	5%,10%	100 MHz,200 mV	12	1900	0.45	500
CF160808T-33N□	33	5%,10%	100 MHz,200 mV	12	1600	0.55	400
CF160808T-39N□	39	5%,10%	100 MHz,200 mV	12	1400	0.6	400
CF160808T-47N□	47	5%,10%	100 MHz,200 mV	12	1300	0.7	400
CF160808T-56N□	56	5%,10%	100 MHz,200 mV	12	1100	0.75	400

## High Frequency Chip Inductor / CF TYPE

### Electrical Characteristics ( CF16080808 TYPE )

Part No.	Inductance (nH)	Tolerance ( $\pm$ )	L,Q Test Freq. (MHz)	Q Min	SRF (MHz)Typ.	DCR ( $\Omega$ ) Max	Rated Current (mA) Max
CF160808T-62N□	62	5%,10%	100 MHz,200 mV	12	1050	0.85	400
CF160808T-68N□	68	5%,10%	100 MHz,200 mV	12	1050	0.85	400
CF160808T-75N□	75	5%,10%	100 MHz,200 mV	12	900	1	300
CF160808T-82N□	82	5%,10%	100 MHz,200 mV	12	900	1	300
CF160808T-R10□	100	5%,10%	100 MHz,200 mV	12	770	1.2	300
CF160808T-R12□	120	5%,10%	50 MHz,200 mV	8	850	2.3	300
CF160808T-R15□	150	5%,10%	50 MHz,200 mV	8	550	2.4	250
CF160808T-R18□	180	5%,10%	50 MHz,200 mV	8	520	2.7	250
CF160808T-R22□	220	5%,10%	50 MHz,200 mV	8	500	3	250

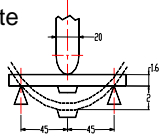
#### NOTE:

1. Operating temperature range  $-55^{\circ}\text{C} \sim 125^{\circ}\text{C}$
2. Rate Current : Applied the current to coils, the temperature rise shall not be more than  $30^{\circ}\text{C}$
3. □Tolerance : C= $\pm 0.2\text{nH}$  ; S= $\pm 0.3\text{nH}$  ; J= $\pm 5\%$  ; K= $\pm 10\%$

## High Frequency Chip Inductor / CF TYPE

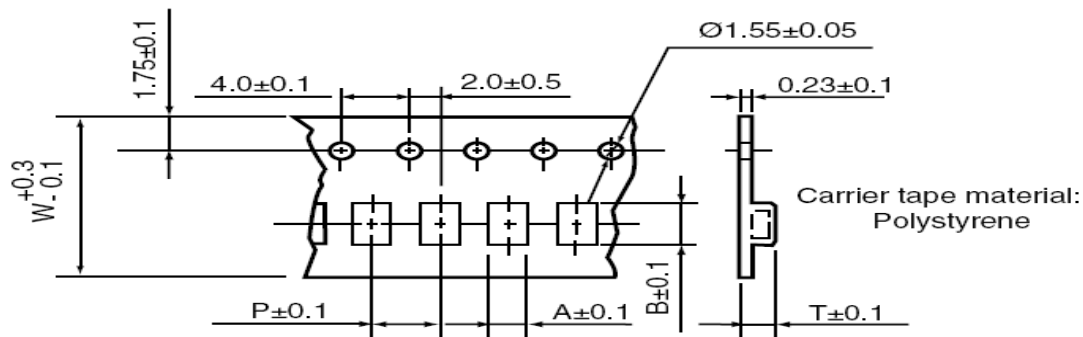
### 4. Reliability and Test Conditions(可靠性測試條件)

#### 1-1.Mechanical Performance

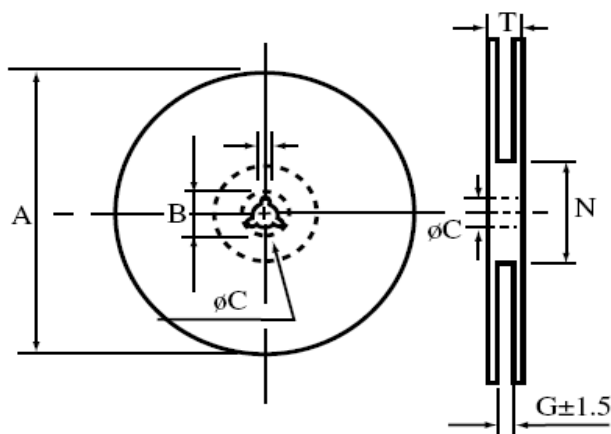
Item	Specification	Test Method															
Flexure Strength	The forces applied on the right conditions must not damage the terminal electrode and the ferrite	Test device shall be soldered on the substrate Substrate Dimension: 100x40x1.6mm Deflection: 2.0mm Keeping Time: 30sec *For 100505, substrate dimension is 100x40x0.8mm 															
Vibration		Test device shall be soldered on the substrate Oscillation Frequency: 10 to 55 to 10Hz for 1min Amplitude: 1.5mm Time: 2hrs for each axis (X, Y & Z), total 6hrs															
Resistance to Soldering Heat	Appearance: No damage	Pre-heating: 150°C, 1min Solder Composition: Sn/Pb = 63/37 Solder Composition: Sn/Ag3.0/Cu0.5(Pb-Free) Solder Temperature: 260±5°C Immersion Time: 10±1sec															
Solder ability	The electrodes shall be at least 90% covered with new solder coating	Pre-heating: 150°C, 1min Solder Composition: Sn/Pb = 63/37 Solder Temperature: 220±5°C Solder Composition: Sn/Ag3.0/Cu0.5(Pb-Free) Solder Temperature: 245±5°C (Pb-Free) Immersion Time: 4±1sec															
Temperature Cycle	Appearance: No damage Inductance: within±10% of initial value Q change: within±30% of initial value	One cycle: <table border="1" data-bbox="826 1288 1273 1467"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> <th>Time (min)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>-55±3</td> <td>30</td> </tr> <tr> <td>2</td> <td>25±2</td> <td>3</td> </tr> <tr> <td>3</td> <td>125±3</td> <td>30</td> </tr> <tr> <td>4</td> <td>25±2</td> <td>3</td> </tr> </tbody> </table> Total: 100cycles Measured after exposure in the room condition for 24hrs	Step	Temperature (°C)	Time (min)	1	-55±3	30	2	25±2	3	3	125±3	30	4	25±2	3
Step		Temperature (°C)	Time (min)														
1		-55±3	30														
2		25±2	3														
3		125±3	30														
4	25±2	3															
Humidity Resistance	Temperature: 40±2°C Relative Humidity: 90 ~ 95% / Time: 1000hrs Measured after exposure in the room condition for 24hrs																
High Temperature Resistance	Temperature: 125±3°C Relative Humidity: 20% Applied Current: Rated Current / Time: 1000hrs Measured after exposure in the room condition for 24hrs																
Low Temperature Resistance	Temperature: -55±3°C Relative Humidity: 0% / Time: 1000hrs Measured after exposure in the room condition for 24hrs																

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### .Packing Specifications



TYPE	Packaging Quantity		Tape Dimension				
	Pcs / Reel	Inner box	A	B	W	P	T
<b>CF100505</b>	10000	50000	0.65	1.12	8	2	0.60
<b>CF160808</b>	4000	20000	1.00	1.80	8	4	0.95



TYPE	Reel Dimension					
	A	B	C	G	N	T
8mm	178±2	21.0±0.8	13.0±0.8	10	75	12.5